Amendments to the Specification:

Please replace the paragraph, beginning at page 2, line 14, with the following rewritten paragraph:

~~Fig.~~Figs. 1 A and 1B are ~~is an~~ equivalent circuit diagrams of a high frequency switch in accordance with a first exemplary embodiment of the present invention.

Please replace the paragraph, beginning at page 3, line 1, with the following rewritten paragraph:

Fig. 1A is a circuit diagram of a high frequency switch employed in an RF circuit of a mobile phone. This high frequency switch basically includes first field-effect transistor switch (FET switch) 3 connected between input/output (I/O) port 1 and transmission port 2, strip line 5 connected between I/O port 1 and reception port 4, second field-effect transistor switch (FET switch) 6 connected between strip line 5 to the side of reception port 4 and a ground, and control port 7 which controls ON and OFF of the above two FET switches 3 and 6.

Please replace the paragraph, beginning at page 4, line 6, with the following rewritten paragraph:

More specifically, low-pass filter 8 configured with an LC circuit is connected to the side of transmission port 2 of the above high frequency switch, and reception filter 9 is connected to the side of reception port 4. Fig. 2 depicts this configuration. Low-pass filter 8 configured with the LC circuit is formed by an inner layer of dielectric multilayer board 10, and reception filter 9 is mounted on this multilayer board 10. The high frequency switch shown in Fig. ~~1~~ 1A is made by integrally forming two FET switches 3 and 6 by semiconductor element 11 and mounting this semiconductor element 11 on the top face of multilayer board 10. Remaining strip line 5 is formed in an inner layer of multilayer board 10. These components are appropriately connected using connection electrodes such as via holes.

Please replace the paragraph, beginning at page 5, line 7, with the following rewritten paragraph:

As shown in Fig. 1B, in reception filter 9 connected to reception port 4, via a capacitor 15, a path from reception port 4 to a later step is preferably made of a high frequency filter such as a band pass filter and SAW filter connected by capacitive coupling of a capacitor 15. This is because the capacitive coupling can also be used as a capacitor for cutting the DC component in the control voltage applied from control port 7.